

## 产品规格书

### Specifcation of products

产品名称: 整流单管模块

产品型号: MD250A-Y12

浙江世菱半导体有限公司  
ZHEJIANG SHILING SEMICONDUCTOR CO., LTD.

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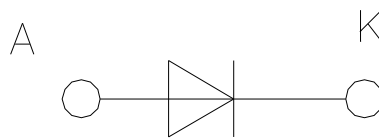
Http://www.smrshiling.com

拟制	审核	核准
林益龙	曹剑龙	宗瑞

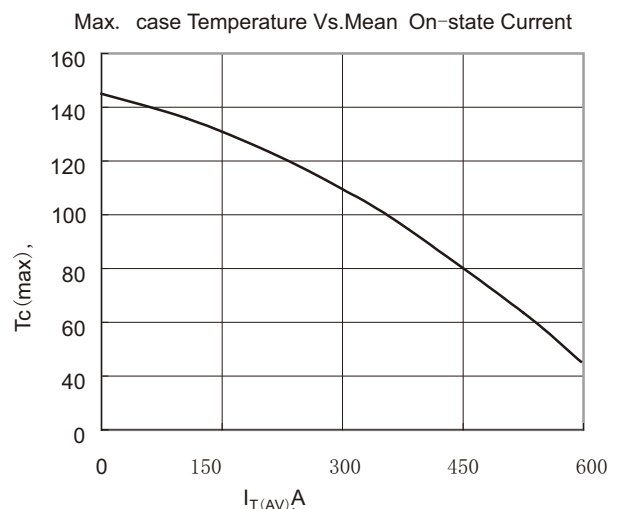
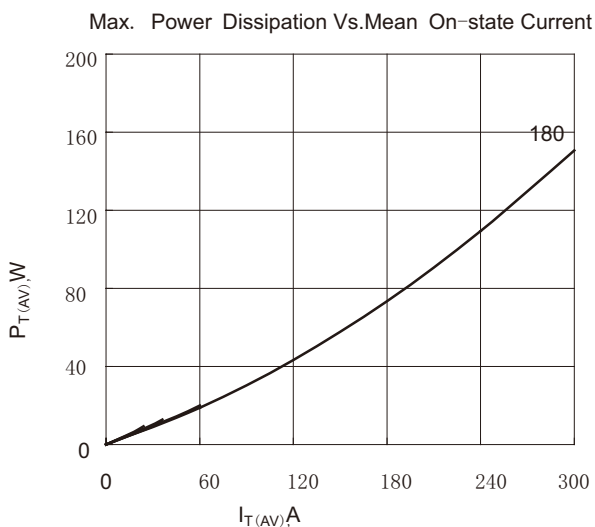
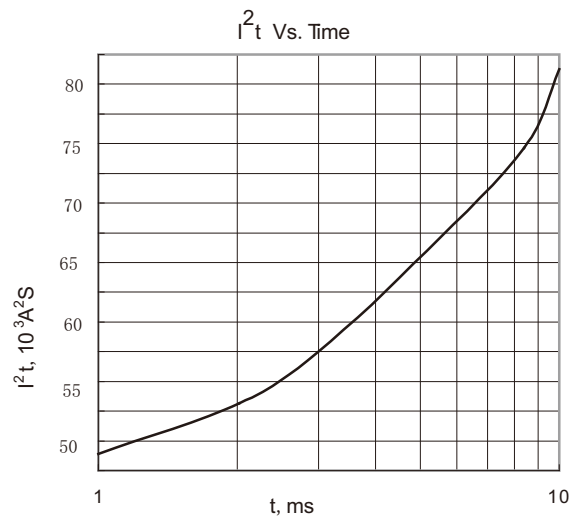
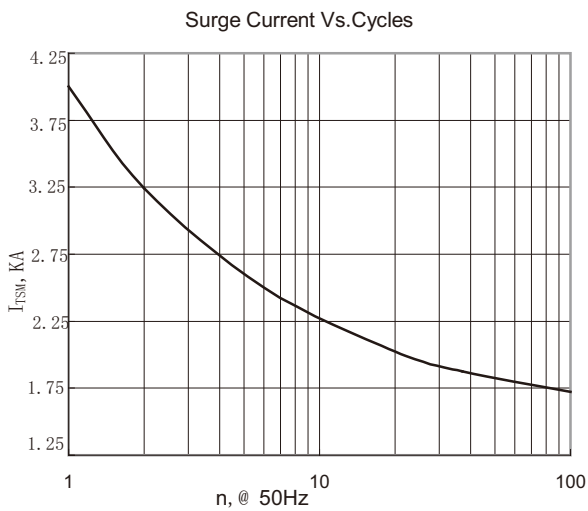
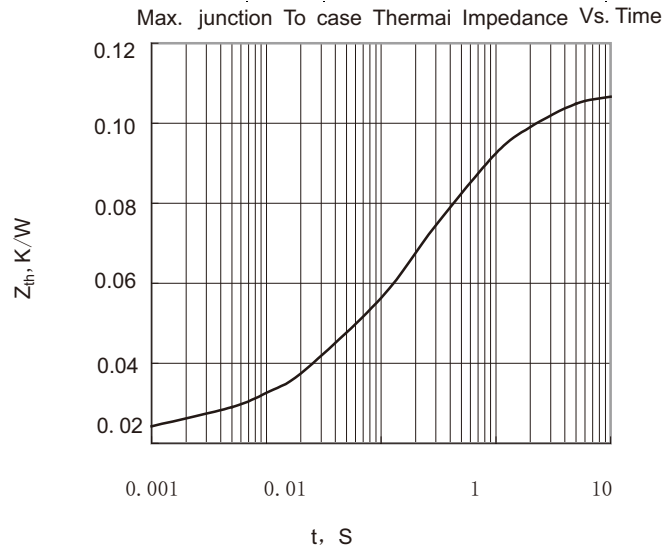
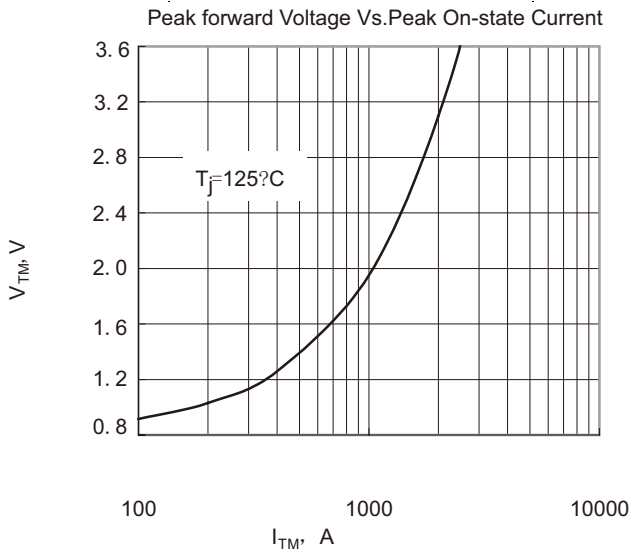
SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T <sub>j</sub> (°C)	VALUE			UNIT
				Min	Type	Max	
I <sub>F(AV)</sub>	Mean for ward current	180° half sine wave 50Hz Single side cooled,T <sub>C</sub> =100°C	150			250	A
I <sub>F(RMS)</sub>	RMS for ward current	Single side cooled,T <sub>C</sub> =100°C	150			393	A
V <sub>RRM</sub>	Repetitive peak reverse voltage	V <sub>RRM</sub> tp=10ms V <sub>RSM</sub> = V <sub>DRM</sub> &V <sub>RRM</sub> +200V	150	600		1800	V
I <sub>RRM</sub>	Repetitive peak current	at V <sub>RRM</sub>	150			20	mA
I <sub>FSM</sub>	Surge for ward current	10ms half sine wave	150			12.5	KA
I <sup>2</sup> t	I <sup>2</sup> T for fusing coordination	V <sub>R</sub> =0.6V <sub>RRM</sub>					797
V <sub>FO</sub>	Threshold voltage		150			0.75	V
r <sub>F</sub>	Forward slop resistance						0.55
V <sub>FM</sub>	Peak for ward voltage	I <sub>FM</sub> =750A	25			1.1	V
R <sub>th(j-c)</sub>	Thermal resistance Junction to heatsink	At 180° sine Single side cooled				0.130	°C/W
V <sub>iso</sub>	Isolation voltage	50Hz, RM. S, t=1min, I <sub>iso</sub> : 1mA (max)		2500			V
F <sub>m</sub>	Terminal connection torque( M6)				4.0		N.m
	Mounting torque( M8)				7.0		N.m
T <sub>stg</sub>	Stored temperature			-40		125	°C
W <sub>t</sub>	Weight				900		g
Outline							

### OUTLINE DR AWING & CIRCUIT DIAGRAM

# MD



## Rating and Characteristic



## Outside Dimension

